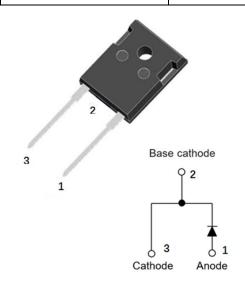


Silicon Carbide Schottky Diode

V_{RRM}	1200V
I _{F (135°C)}	42A
Qc	162nC



Features

- Positive temperature coefficient
- Temperature-independent switching
- Maximum working temperature at 175 °C
- Unipolar devices and zero reverse recovery current
- Zero forward recovery current
- Essentially no switching losses
- Reduction of heat sink requirements
- High-frequency operation
- Reduction of EMI

Typical Applications

Typical applications are in power factor correction(PFC), solar inverter, uninterruptible power supply, motor drives, photovoltaic inverter, electric car and charger.

Mechanical Data

• Package: TO-247AC

• Terminals: Tin plated leads

• Polarity: As marked

■Maximum Ratings (T_c=25°C Unless otherwise specified)

PARAMTETER	SYMBOL	UNIT	VALUE
Device marking code			D112030NQG2
Reverse voltage (repetitive peak) @ T _j =25°C	V_{RRM}	V	1200
Reverse voltage (Surge Peak) @ T _j =25°C	V_{RSM}	V	1200
Reverse voltage (DC) @ T _j =25°C	V _{DC}	٧	1200
Continuous forward current @ T _c =25°C T _c =135°C T _c =152°C	I _F	А	94 43 30
Non-repetitive peak forward surge current @ T _c =25°C, tp=10ms, Half Sine Wave	I _{FSM}	А	225
Power Dissipation@ T _c =25°C T _c =110°C	P _{TOT}	W	416 180
i²t Value@ Tc=25°C ,tp=10ms	∫ i²dt	A ² S	253
Operating junction and Storage temperature range	T_{j} , T_{stg}	°C	-55 to +175

YJD112030NQG2



■Electrical Characteristics

PARAMTETER	SYMBOL	UNIT	TEST CONDITIONS	Тур.	Max.
Forward voltage drop	V _F	V	I _F =30A, T _j =25°C	1.43	1.58
			I _F =30A, T _j =175°C	1.97	
Poverce leakage current	I _R	μA	V _R =1200V, T _j =25°C	3.4	30
Reverse leakage current			V _R =1200V, T _j =175°C	20.3	
Total capacitive charge	Qc	nC	V_R =800V, T_j =25°C , QC = $\int_0^{VR}C(V)dV$	162	
Total capacitance	С	pF	V _R =0V, f=1MHZ	2179	
			V _R =400V, f=1MHZ	152	
			V _R =800V, f=1MHZ	118	
Capacitance Stored Energy	Ec	μJ	V _R =800V	42	

■Thermal Characteristics $(T_a=25$ $^{\circ}$ C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	VALUE
Thermal resistance	$R_{\theta J-C}$	°C W	0.36

■Characteristics (Typical)

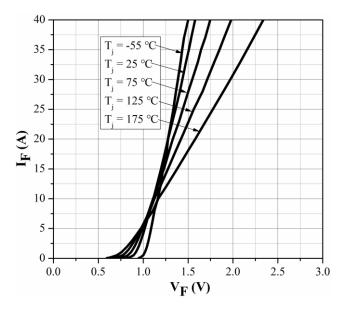


Figure 1. Forward Characteristics

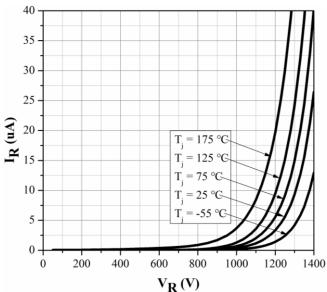


Figure 2. Reverse Characteristic



0

25

75

50

100

 $T_{\mathbb{C}}({}^{\circ}\mathbb{C})$



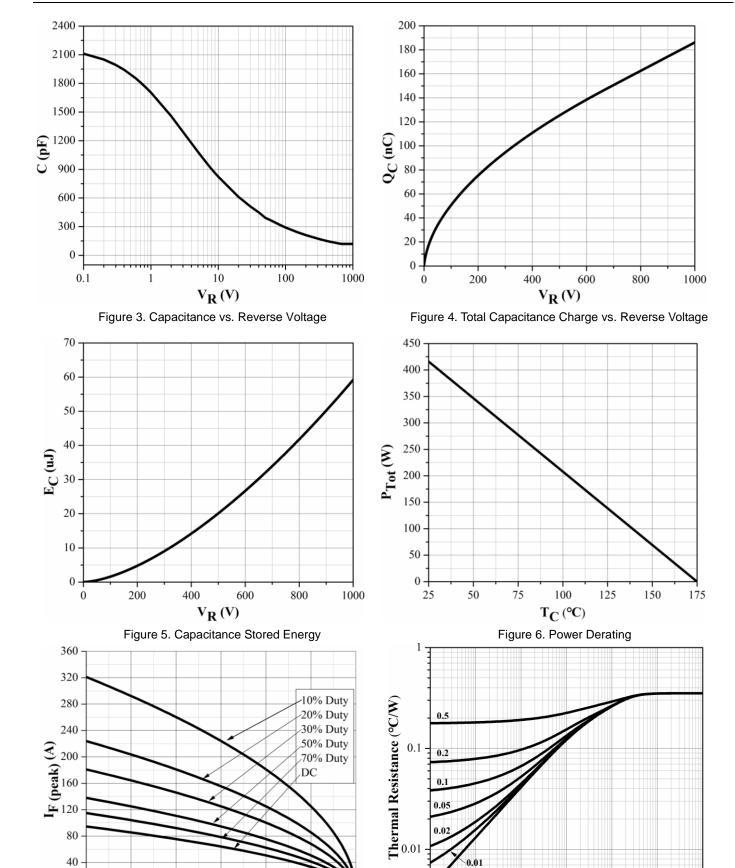


Figure 7. Current Derating Figure 8. Transient Thermal Impedance

1E-6

1E-5

1E-4

1E-3

T (Sec)

0.01

175

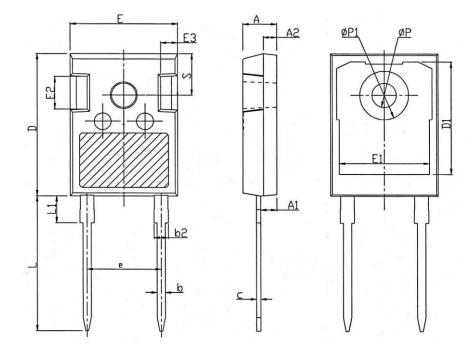
150

0.1





■Outline Dimensions



TO247-AC				
Dim	Min	Max		
Α	4.80	5.20		
A1	2.21	2.61		
A2	1.85	2.15		
b	1.11	1.36		
b2	1.91	2.21		
С	0.51	0.75		
D	20.70	21.30		
D1	16.25	16.85		
Е	15.50	16.10		
E1	13.00	13.60		
E2	4.80	5.20		
E3	2.30	2.70		
е	10.88BSC			
L	19.62	20.22		
L1	-	4.30		
φΡ	3.40	3.80		
φΡ1	-	7.30		
S	6.15BSC			



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